

VS-20UT04, VS-20WT04FN

Vishay Semiconductors

RoHS

COMPLIANT

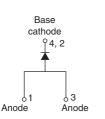
High Performance Schottky Generation 5.0, 20 A

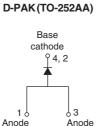


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I-PAK(TO-251AA)





VS-20UT04

VS-20WT04FN

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)			
IF(AV)	20 A			
V _R	45 V			
V _F at I _F	0.53 V			
I _{RM} max.	7 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	108 mJ			

FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_R trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Specific for PV cells bypass diode
- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- · Increased power density systems

Note

• V_F measured at 125 °C, connecting 2 anode pins

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V _{RRM}		45	V		
V _F	20 Apk, T _J = 125 °C (typical, measured connecting 2 anode pins)	0.480	V		
TJ	Range	- 55 to 175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20UT04 VS-20WT04FN	UNITS
Maximum DC reverse voltage	V _R	T _J = 25 °C	45	V

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_{C} = 153 °C, rectangular waveform		20	А
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied ⁽¹⁾	900	A
		10 ms sine or 6 ms rect. pulse		220	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 7 \text{ A}, L = 4.4 \text{ mH}$		108	mJ
Repetitive avalanche current	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse		l _{AS} at T _J max.	А

Note

⁽¹⁾ Measured connecting 2 anode pins

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop	V _{FM} ⁽¹⁾⁽²⁾	10 A	- T _J = 25 °C	0.505	0.540	
		20 A		0.570	0.610	V
		10 A	- T _J = 125 °C	0.415	0450	v
		20 A		0.520	0.580	
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	-	100	μA
		T _J = 125 °C		-	7	mA
Junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1900	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body		-	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

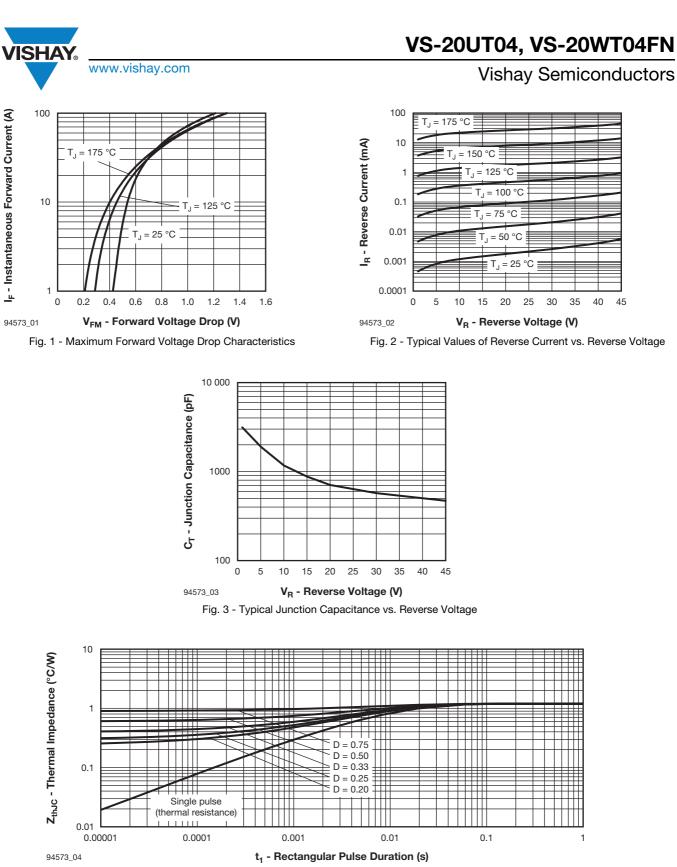
Notes

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

⁽²⁾ Only 1 anode pin connected

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.2	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}		0.3	0/10
Approvimete weight			2	g
Approximate weight			0.07	oz.
		Case style I-PAK	20U	T04
Marking device		Case style D-PAK	20WT	04FN

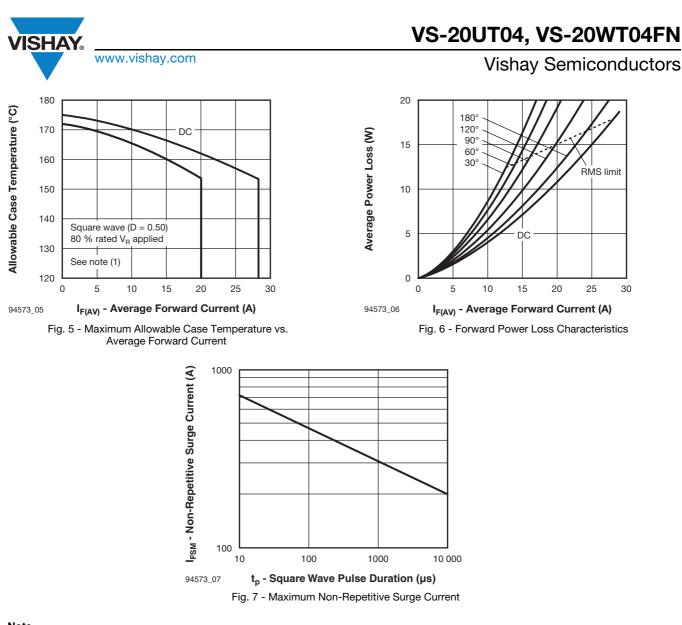
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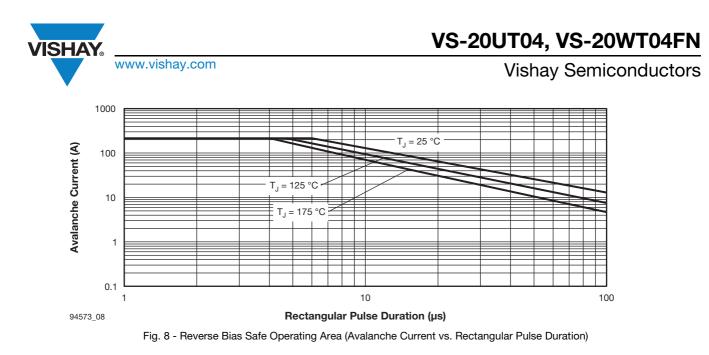
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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); I}_{R} \mbox{ at } \mbox{V}_{R1} = 80 \ \% \mbox{ rated V}_{R} \end{array}$



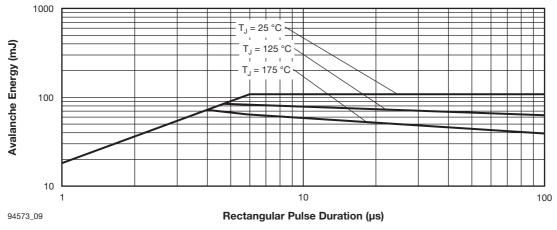


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



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ORDERING INFORMATION TABLE

Device code VS-20 U Т 04 FN TRL (2) 6 1 (3) (4)(5) 7 1 Vishay Semiconductors product 2 Current rating (20 A) 3 Package: • U = I-PAK •W = D-PAK 4 T = Trench 5 6 Voltage code (45 V) TO-252AA (D-PAK) 7 D-PAK, I-PAK: None = Tube (75 pieces) D-PAK only: • TR = Tape and reel

- TRL = Tape and reel (left oriented)
- TRR = Tape and reel (right oriented)

LINKS TO RELATED DOCUMENTS				
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024		
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448		
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025		
	D-PAK (TO-252AA)	www.vishay.com/doc?95059		
Packaging information		www.vishay.com/doc?95033		
SPICE model		www.vishay.com/doc?95027		

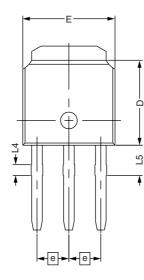


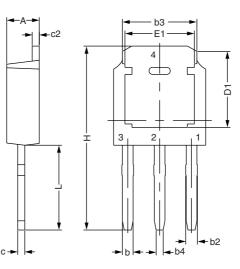
Outline Dimensions

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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





	DIMENSIONAL REQUIREMENTS				
SYMBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41 0.51		0.61		
е	2.286 BSC				
A	2.20	2.30	2.38		
С	0.40	0.50	0.60		
c2	0.40	0.50	0.60		
D1	5.30	-	-		
E1	4.40	-	_		

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